

# Simulating LEM gain in DUNE DP using legacy LArG4

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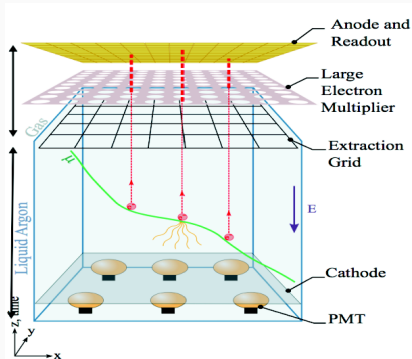
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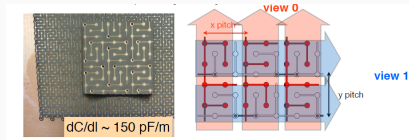
# Table of contents

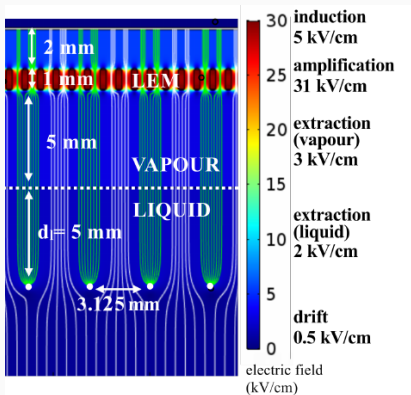
1. Dual Phase
2. LegacyLArG4
3. Refactored for Dual Phase

# Dual Phase



Dual-Phase has additional steps to Single-Phase LArTPCs. Electrons are extracted into the gas. In the LEM holes, Townsend avalanches occur. Electrons are collected on two split anodes.





It would be great if we could  
simulate various operating voltages

Of interest:

Efficiency of electron extraction

Efficiency of entering LEM holes

LEM gain

Efficiency of anode collection

Noting:

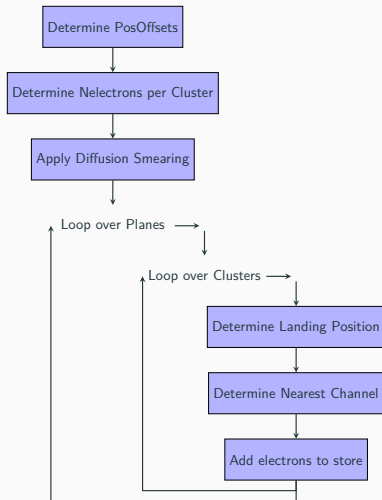
The LEMs (10cm\*10cm panels) are  
not all operating at the same  
voltages (different gains)

Data taken so far with  
protoDUNE-DP has a very  
non-uniform field due to a short of  
the field cage

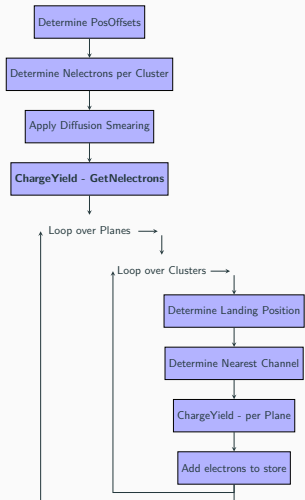
# LegacyLArG4

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In void LArVoxelReadout::DriftIonizationElectrons(..).



Landing positions are calculated and used to find the Nearest Channels. Electrons are collected and stored in SimChannels (per wire). The SpaceCharge module is used to deal with our non-uniform Electric field. But, we lose the 2D information (landing position), and so we can not apply correctly any gain variations. We also have difficulty with collection planes (correlation of number of electrons detected per cluster per plane).



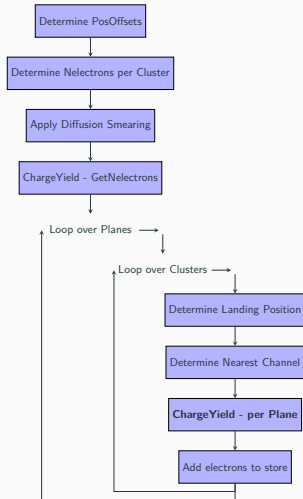
Following structure of the SpaceCharge service.. Create a ChargeYieldService, that will do the amplification process

```

auto const* CYE = lar::providerFrom<chargeyield::
    ChargeYieldService>();
if (CYE->EnableChargeYield() == true)
{
    for(int k = 0; k < nClus; ++k){
        //calculate the number of electrons after
        //charge multiplication at first plane
        nEIDiff[k]= CYE->GetNElectrons(cryostat ,
            tpc ,
            { tpcg.PlaneLocation(0)[0] - tpcg.
                PlanePitch(0)), YDiff[k], ZDiff[k]
            },
            TDrift , nEIDiff[k]);
    }
}

```

and charge sharing before electrons are stored in SimChannels.



```

..
// Drift nClus electron clusters to the
// induction plane
for(int k = 0; k < nClus; ++k){
..

//if using ChargeYield module —> calculate
// electron signals per plane
double nel=nEIDiff[k];
if (C YE->EnableChargeYield() == true)
{ //calculate how many electrons on each
plane
nel= C YE->GetNElectronsPlane(cryostat
,tpc, p, nEIDiff[k]);
//planes can be collection or
induction
nEIDiff[k] = C YE->
GetRemainingElectrons(nEIDiff[
k], nel);
if(nel<=0) continue;
}
// Add electrons produced by each cluster
to the map
DepositsToStore[channel][tdc].add(nEnDiff
[k], nel);
}
}

```

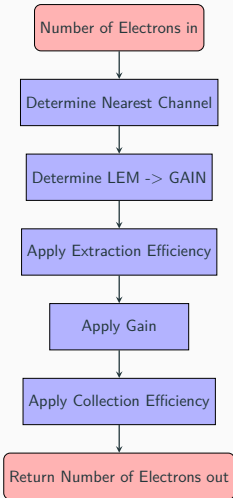
larevt/ChargeYieldStandard - does nothing. No change to normal working.

dunetpc/ChargeYieldProtoDUNE dp - implements:

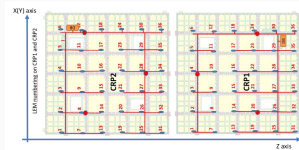
- Configurable voltages (for all 144 LEMs and grids) or Effective Gain settings
- Statistics on LEM gain (if required)
- Configurable efficiencies on electron extraction and collection



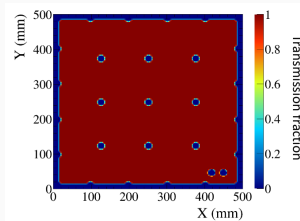
```
double chargeyield::ChargeYieldProtoDUNEdp::GetNElectrons( unsigned
short int cryostat, unsigned short int tpc, geo::Point_t const& point,
double tdrift, double Nelec_in)
```



## LEM mapping



## LEM dead areas



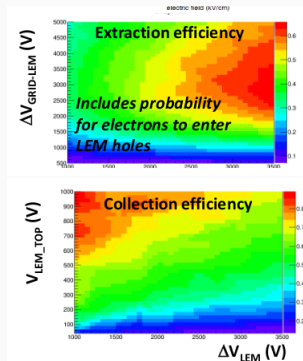
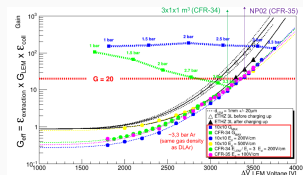
## Two possibilities for the GAIN (fcl)

```
UseEffectiveGain: true
EffectiveGain: [0,0,0,1.22,0,0, ...144
               entries..]
```

or via Voltages

```
CRPVoltFilename: "DB\_run1415.output.  
CRPVoltages" # file holding all  
voltages  
defaultCollectionEfficiency: 0.7  
defaultExtractionEfficiency: 1.0  
CRPsimFilename: "" # to come  
Lem_A: 1646.99  
Lem_B: 131.96
```

## LEM lab gain measurements



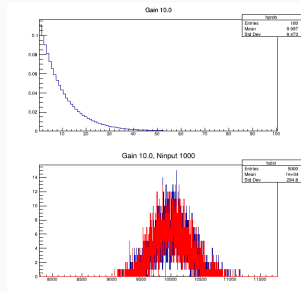
if

EnableRandom : **true**

then sample LEM gain fom Furry distribution.

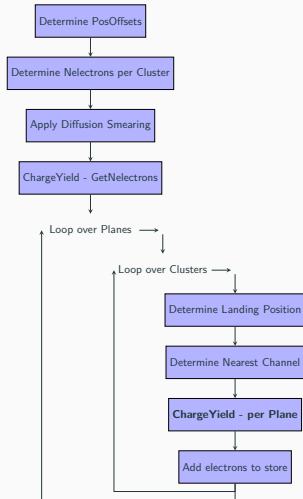
If the number of electrons is low, distributions are non-Gaussian.

Example for a gain of 10 and 1000 input electrons.



Otherwise just use mean gain.

and charge sharing before electrons are stored in SimChannels.



```

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// Drift nClus electron clusters to the
// induction plane
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..

//if using ChargeYield module —> calculate
// electron signals per plane
double nel=nEIDiff[k];
if (C YE->EnableChargeYield() == true)
{ //calculate how many electrons on each
plane
nel= C YE->GetNElectronsPlane(cryostat
,tpc, p, nEIDiff[k]);
//planes can be collection or
induction
nEIDiff[k] = C YE->
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k], nel);
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[k], nel);
}
}

```

```

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// Drift nClus electron clusters to the
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  for(int k = 0; k < nClus; ++k){
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        nel= C YE->GetNElectronsPlane(cryostat
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        //planes can be collection or
          induction
        nEIDiff[k] = C YE->
          GetRemainingElectrons(nEIDiff[
            k], nel);
        if(nel<=0) continue;
      }
    // Add electrons produced by each cluster
      to the map
    DepositsToStore[channel][tdc].add(nEnDiff[
      k], nel);
  }
}

```

double GetNElectronsPlane(unsigned short int cryostat, unsigned short int tpc, int p, double Nelec;*n*)const and double GetRemainingElectrons(double NeleCluster, double NelePlane) const These two functions deal with the fact that our 2 anodes are collection planes, without it being assumed in LArVoxelReadOut.

## Refactored for Dual Phase

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- Very recently..In use for *Light* simulation (with alternative geometry - ydrift)
- Not yet in use for *Charge* simulation
- We will move towards refactored so OK to implement there
- What do I need?